

TECHNICAL DATA  
DATA SHEET 5338, REV A**THREE PHASE FULL WAVE  
ULTRAFAST BRIDGE RECTIFIER ASSEMBLY**

DESCRIPTION: 600 VOLT, 6 AMP, 180 NANOSECOND THREE PHASE BRIDGE RECTIFIER ASSEMBLY.

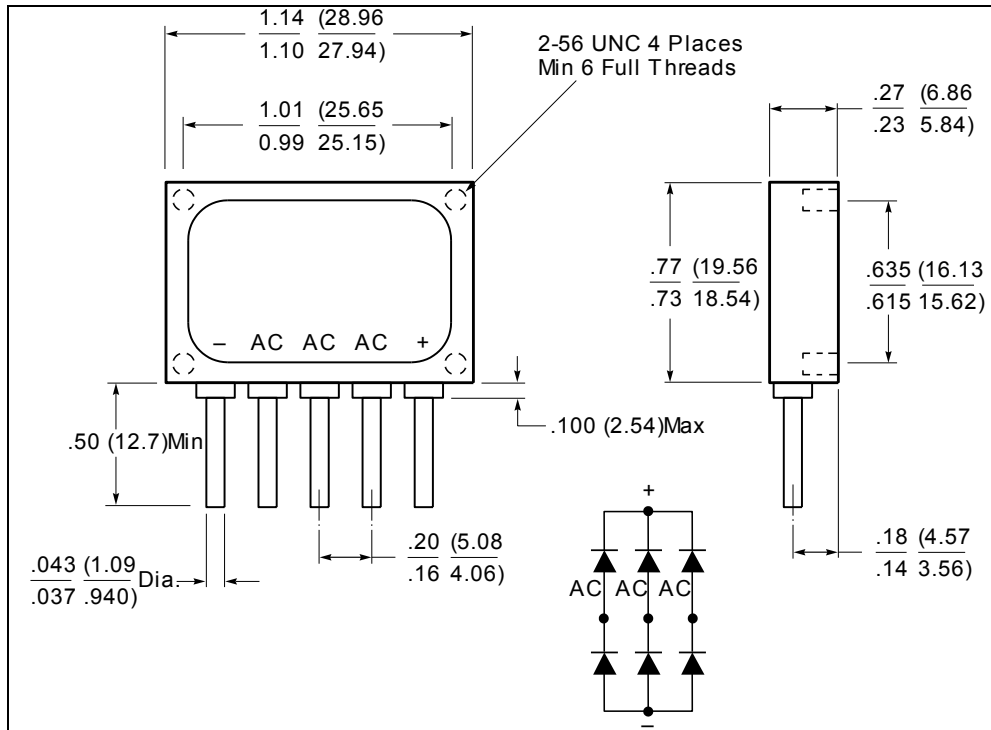
Note: Add 'S' at the end for S-100 Screening

MAX. RATINGS / ELECTRICAL CHARACTERISTICS All ratings are at  $T_A = 25^\circ\text{C}$  unless otherwise specified.

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV)	-	-	-	600	Vdc
Average DC Output Current ( $I_o$ )	$T_C = 55^\circ\text{C}$ $T_C = 100^\circ\text{C}$	-	-	6 4.5	Amps
Peak Single Cycle Surge Current ( $I_{FSM}$ )	$t_p = 8.3$ ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	25	Amps(pk)
Operating and Storage Temp. ( $T_{op}$ & $T_{stg}$ )	-	-55	-	+150	$^\circ\text{C}$
Maximum Forward Voltage ( $V_f$ )	$I_f = 3.0\text{A}$ (300 $\mu\text{sec}$ pulse, duty cycle < 2%)	-	-	1.3	Volts
Maximum Instantaneous Reverse Current At Rated (PIV)	$T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	-	-	5.0 100	$\mu\text{Amps}$
Reverse Recovery Time ( $t_{rr}$ )	$I_f = 0.5\text{A}$ , $I_r = 1.0\text{A}$ , $I_{rr} = 0.25\text{A}$	-	-	180	nsec
Thermal Resistance ( $\theta_{JL}$ )	-	-	-	5	$^\circ\text{C/W}$

**SENSITRON**  
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**MECHANICAL DIMENSIONS: In Inches / mm**



**FIG. 405A**

Note: Case finish - Black Anodized

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